

# 74AUP1G17

Low-power Schmitt trigger

Rev. 8 — 15 January 2015

Product data sheet

## 1. General description

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The 74AUP1G17 provides the single Schmitt trigger buffer. It is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage  $V_H$ .

## 2. Features and benefits

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- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu\text{A}$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot  $< 10\%$  of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^\circ\text{C}$  to  $+85\text{ }^\circ\text{C}$  and  $-40\text{ }^\circ\text{C}$  to  $+125\text{ }^\circ\text{C}$



### 3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74AUP1G17GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G17GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G17GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G17GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G17GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G17GX	-40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226

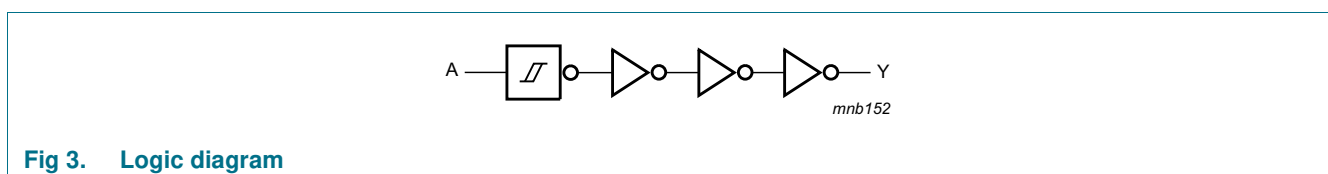
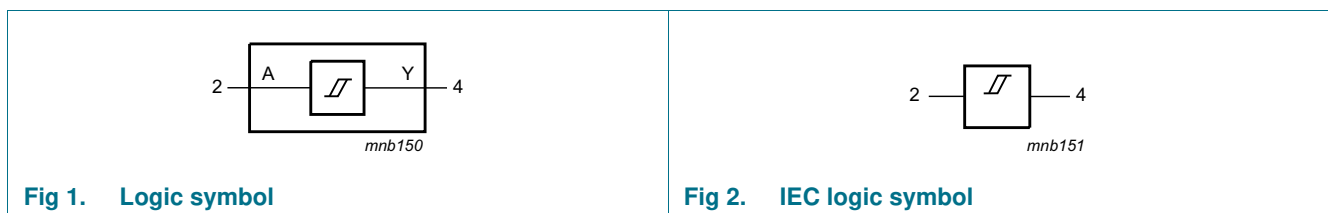
### 4. Marking

Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74AUP1G17GW	pJ
74AUP1G17GM	pJ
74AUP1G17GF	pJ
74AUP1G17GN	pJ
74AUP1G17GS	pJ
74AUP1G17GX	pJ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning

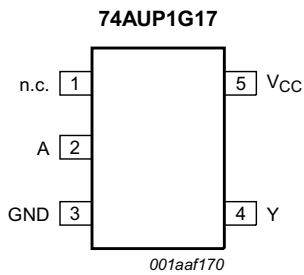


Fig 4. Pin configuration SOT353-1

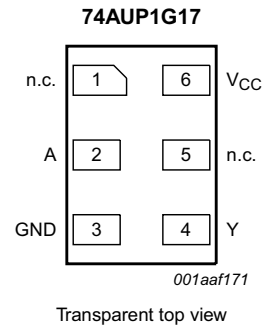


Fig 5. Pin configuration SOT886

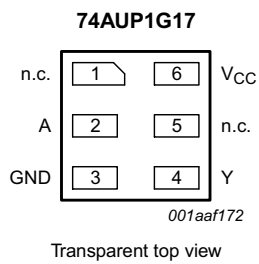


Fig 6. Pin configuration SOT891, SOT1115 and SOT1202

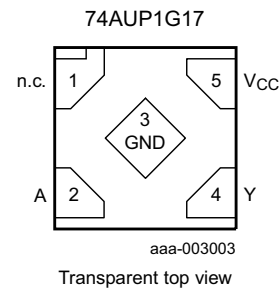


Fig 7. Pin configuration SOT1226 (X2SON5)

### 6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	TSSOP5 and X2SON5	XSON6	
n.c.	1	1	not connected
A	2	2	data input
GND	3	3	ground (0 V)
Y	4	4	data output
n.c.	-	5	not connected
V <sub>CC</sub>	5	6	supply voltage

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Input	Output
A	Y
L	L
H	H

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
$I_{IK}$	input clamping current	$V_I < 0$ V	-50	-	mA
$V_I$	input voltage		<sup>[1]</sup> -0.5	+4.6	V
$I_{OK}$	output clamping current	$V_O < 0$ V	-50	-	mA
$V_O$	output voltage	Active mode and Power-down mode	<sup>[1]</sup> -0.5	+4.6	V
$I_O$	output current	$V_O = 0$ V to $V_{CC}$	-	±20	mA
$I_{CC}$	supply current		-	+50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	<sup>[2]</sup> -	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
$V_I$	input voltage		0	3.6	V
$V_O$	output voltage	Active mode	0	$V_{CC}$	V
		Power-down mode; $V_{CC} = 0$ V	0	3.6	V
$T_{amb}$	ambient temperature		-40	+125	°C

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.2	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	-	-	40	μA
C <sub>I</sub>	input capacitance	V <sub>I</sub> = GND or V <sub>CC</sub> ; V <sub>CC</sub> = 0 V to 3.6 V	-	1.1	-	pF
C <sub>O</sub>	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.7	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V		
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.5	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI <sub>CC</sub>	additional supply current	V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	-	-	50	μA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V		
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V		
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V	-	-	±0.75	μA

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\Delta I_{OFF}$	additional power-off leakage current	$V_I$ or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	$\pm 0.75$	$\mu$ A
$I_{CC}$	supply current	$V_I = GND$ or $V_{CC}$ ; $I_O = 0$ A; $V_{CC} = 0.8$ V to 3.6 V	-	-	1.4	$\mu$ A
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 0.6$ V; $I_O = 0$ A; $V_{CC} = 3.3$ V	-	-	75	$\mu$ A

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#)

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
<b><math>C_L = 5</math> pF</b>									
$t_{pd}$	propagation delay	A to Y; see <a href="#">Figure 8</a> <sup>[2]</sup>							
		$V_{CC} = 0.8$ V	-	19.0	-	-	-	-	ns
		$V_{CC} = 1.1$ V to 1.3 V	2.6	5.7	10.6	2.5	10.9	11.1	ns
		$V_{CC} = 1.4$ V to 1.6 V	2.4	4.2	6.5	2.3	7.1	7.4	ns
		$V_{CC} = 1.65$ V to 1.95 V	2.0	3.6	5.5	1.9	6.1	6.3	ns
		$V_{CC} = 2.3$ V to 2.7 V	1.9	3.0	4.2	1.8	4.6	4.8	ns
		$V_{CC} = 3.0$ V to 3.6 V	1.8	2.7	3.6	1.5	3.8	4.0	ns
<b><math>C_L = 10</math> pF</b>									
$t_{pd}$	propagation delay	A to Y; see <a href="#">Figure 8</a> <sup>[2]</sup>							
		$V_{CC} = 0.8$ V	-	22.5	-	-	-	-	ns
		$V_{CC} = 1.1$ V to 1.3 V	2.9	6.6	12.4	2.7	12.9	13.0	ns
		$V_{CC} = 1.4$ V to 1.6 V	2.6	4.8	7.8	2.4	8.3	8.7	ns
		$V_{CC} = 1.65$ V to 1.95 V	2.5	4.2	6.3	2.4	6.8	7.1	ns
		$V_{CC} = 2.3$ V to 2.7 V	2.3	3.5	4.8	2.1	5.3	5.6	ns
		$V_{CC} = 3.0$ V to 3.6 V	2.1	3.3	4.4	2.0	4.6	4.8	ns
<b><math>C_L = 15</math> pF</b>									
$t_{pd}$	propagation delay	A to Y; see <a href="#">Figure 8</a> <sup>[2]</sup>							
		$V_{CC} = 0.8$ V	-	26.0	-	-	-	-	ns
		$V_{CC} = 1.1$ V to 1.3 V	3.2	7.4	14.1	3.1	14.7	14.9	ns
		$V_{CC} = 1.4$ V to 1.6 V	3.1	5.4	8.7	2.8	9.5	9.9	ns
		$V_{CC} = 1.65$ V to 1.95 V	2.7	4.7	7.1	2.7	7.8	8.2	ns
		$V_{CC} = 2.3$ V to 2.7 V	2.6	4.0	5.6	2.5	6.0	6.3	ns
		$V_{CC} = 3.0$ V to 3.6 V	2.5	3.7	4.9	2.2	5.2	5.5	ns

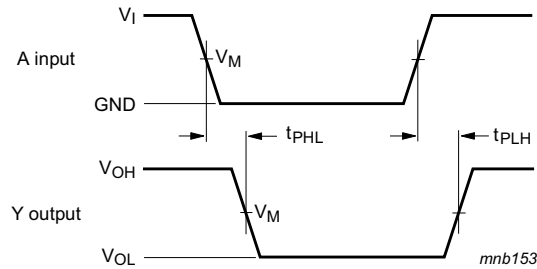
**Table 8. Dynamic characteristics ...continued**  
 Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 9](#)

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
<b>C<sub>L</sub> = 30 pF</b>									
t <sub>pd</sub>	propagation delay	A to Y; see <a href="#">Figure 8</a> <sup>[2]</sup>							
		V <sub>CC</sub> = 0.8 V	-	36.3	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.9	9.7	19.0	3.7	19.8	20.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.5	7.0	11.2	3.6	12.4	13.0	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.5	6.0	9.2	3.4	10.1	10.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.4	5.1	7.0	3.2	7.5	7.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.3	4.8	6.2	3.1	7.1	7.5	ns
<b>C<sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF</b>									
C <sub>PD</sub>	power dissipation capacitance	f = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[3]</sup>							
		V <sub>CC</sub> = 0.8 V	-	2.5	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.7	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.8	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.0	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.5	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.0	-	-	-	pF	

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.



## 12. Waveforms

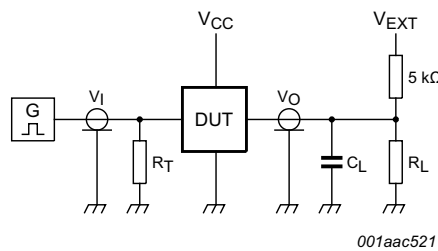


Measurement points are given in [Table 9](#).  
 Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 8. The data input (A) to output (Y) propagation delays**

**Table 9. Measurement points**

Supply voltage	Output	Input		
$V_{CC}$	$V_M$	$V_M$	$V_I$	$t_r = t_f$
0.8 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{CC}$	$\leq 3.0$ ns



Test data is given in [Table 10](#).  
 Definitions for test circuit:  
 $R_L$  = Load resistance.  
 $C_L$  = Load capacitance including jig and probe capacitance.  
 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.  
 $V_{EXT}$  = External voltage for measuring switching times.

**Fig 9. Test circuit for measuring switching times**

**Table 10. Test data**

Supply voltage	Load		$V_{EXT}$		
$V_{CC}$	$C_L$	$R_L$ [1]	$t_{PLH}, t_{PHL}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times,  $R_L = 5$  kΩ, for measuring propagation delays, setup and hold times and pulse width  $R_L = 1$  MΩ.

### 13. Transfer characteristics

**Table 11. Transfer characteristics**

Voltages are referenced to GND (ground = 0 V).

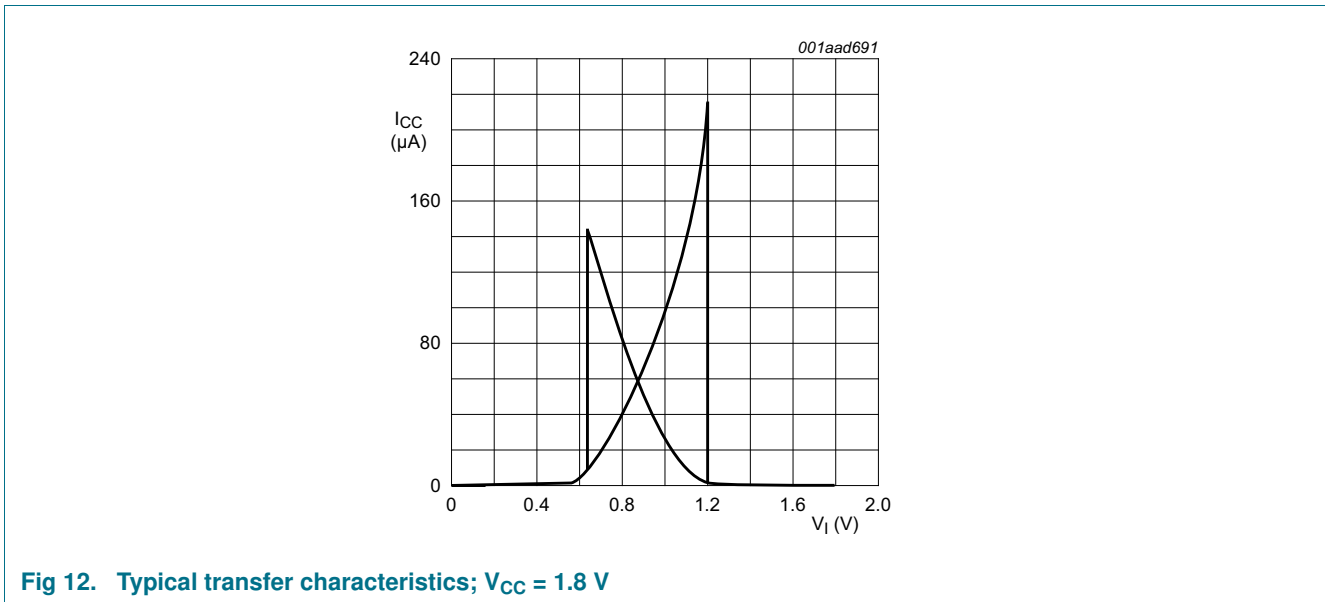
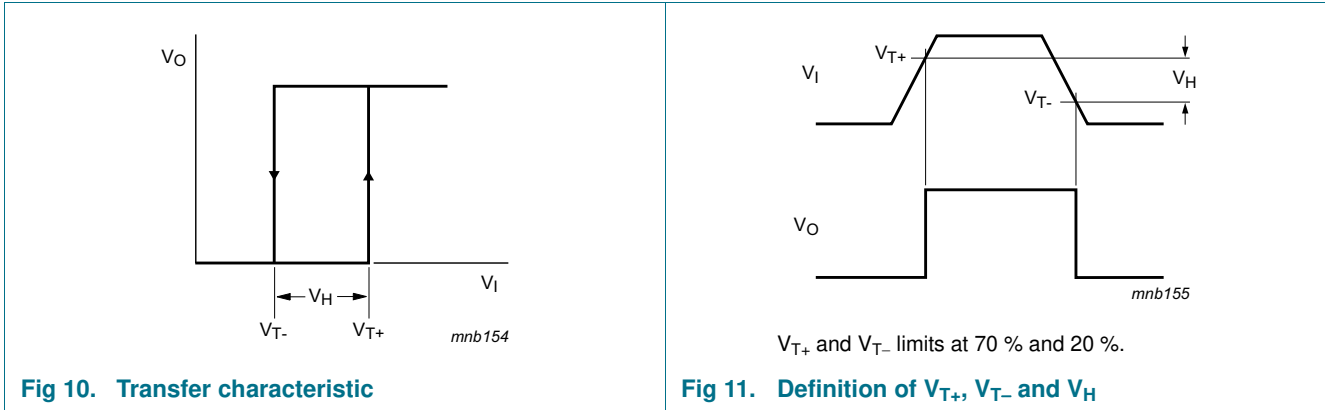
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>T+</sub>	positive-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	V
V <sub>T-</sub>	negative-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	V
V <sub>H</sub>	hysteresis voltage	see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> , <a href="#">Figure 12</a> and <a href="#">Figure 13</a>				
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	V
V <sub>T+</sub>	positive-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	V
V <sub>T-</sub>	negative-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	V
V <sub>T+</sub>	positive-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	V
V <sub>T-</sub>	negative-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	V
V <sub>T+</sub>	positive-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	V
V <sub>T-</sub>	negative-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	V

**Table 11. Transfer characteristics ...continued**

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>H</sub>	hysteresis voltage	see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> , <a href="#">Figure 12</a> and <a href="#">Figure 13</a>				
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	V
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>T+</sub>	positive-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.30	-	0.62	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.32	V
V <sub>T-</sub>	negative-going threshold voltage	see <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	V
V <sub>H</sub>	hysteresis voltage	see <a href="#">Figure 10</a> , <a href="#">Figure 11</a> , <a href="#">Figure 12</a> and <a href="#">Figure 13</a>				
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	V

14. Waveforms transfer characteristics



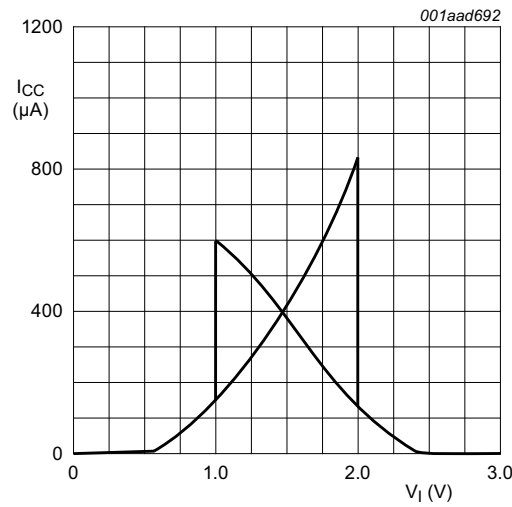


Fig 13. Typical transfer characteristics; V<sub>CC</sub> = 3.0 V

## 15. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$P_{ad} = f_i \times (t_r \times I_{CC(AV)} + t_f \times I_{CC(AV)}) \times V_{CC}$  where:

$P_{ad}$  = additional power dissipation (µW);

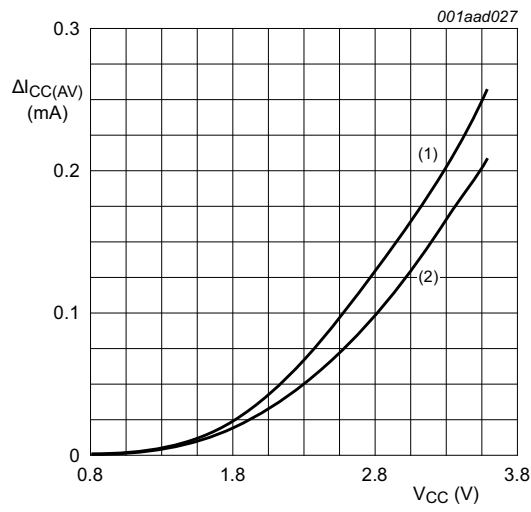
$f_i$  = input frequency (MHz);

$t_r$  = input rise time (ns); 10 % to 90 %;

$t_f$  = input fall time (ns); 90 % to 10 %;

$I_{CC(AV)}$  = average additional supply current (µA).

Average I<sub>CC</sub> differs with positive or negative input transitions, as shown in [Figure 14](#).



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of V<sub>I</sub> between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

**Fig 14. Average I<sub>CC</sub> as a function of V<sub>CC</sub>**

16. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

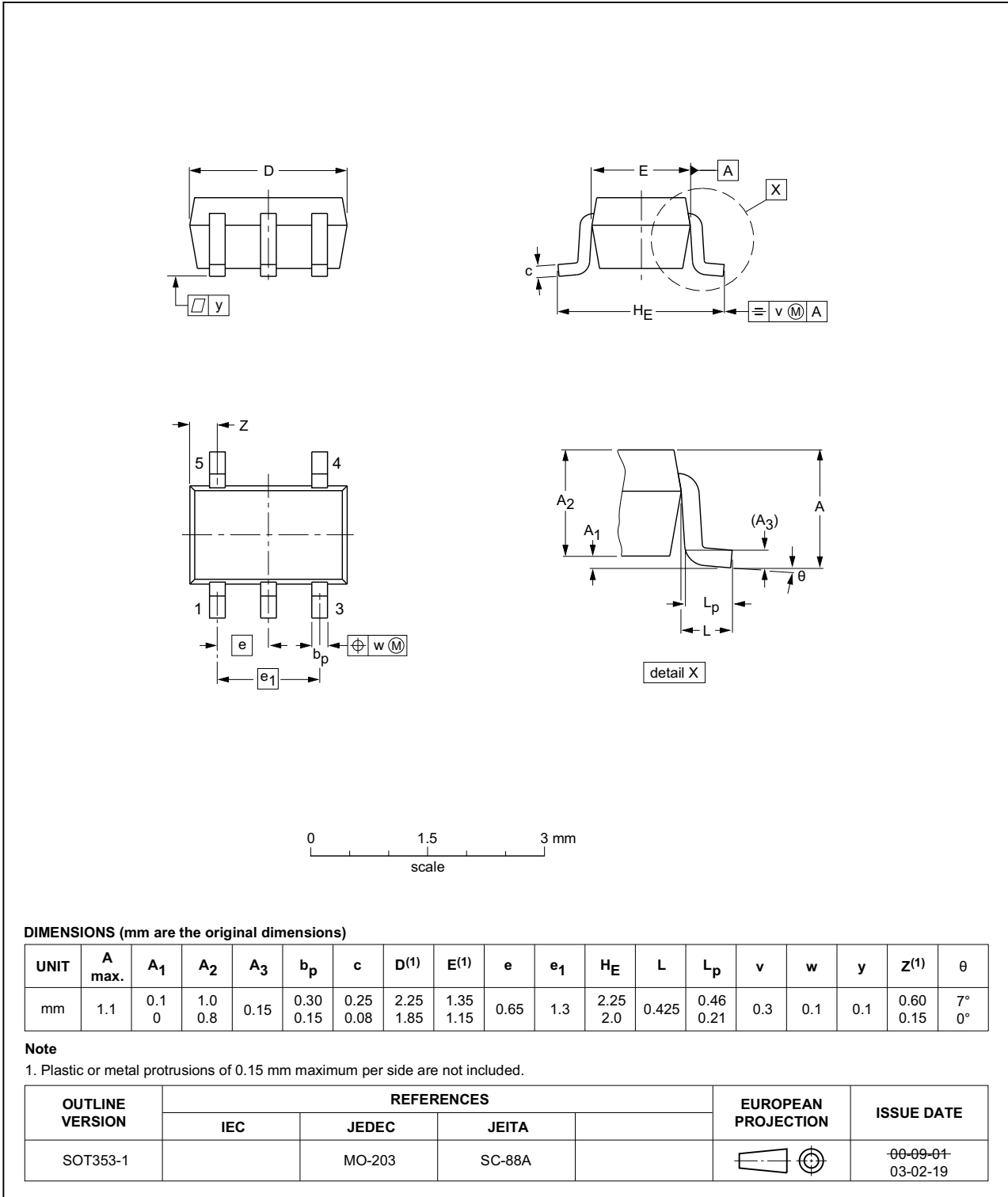


Fig 15. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

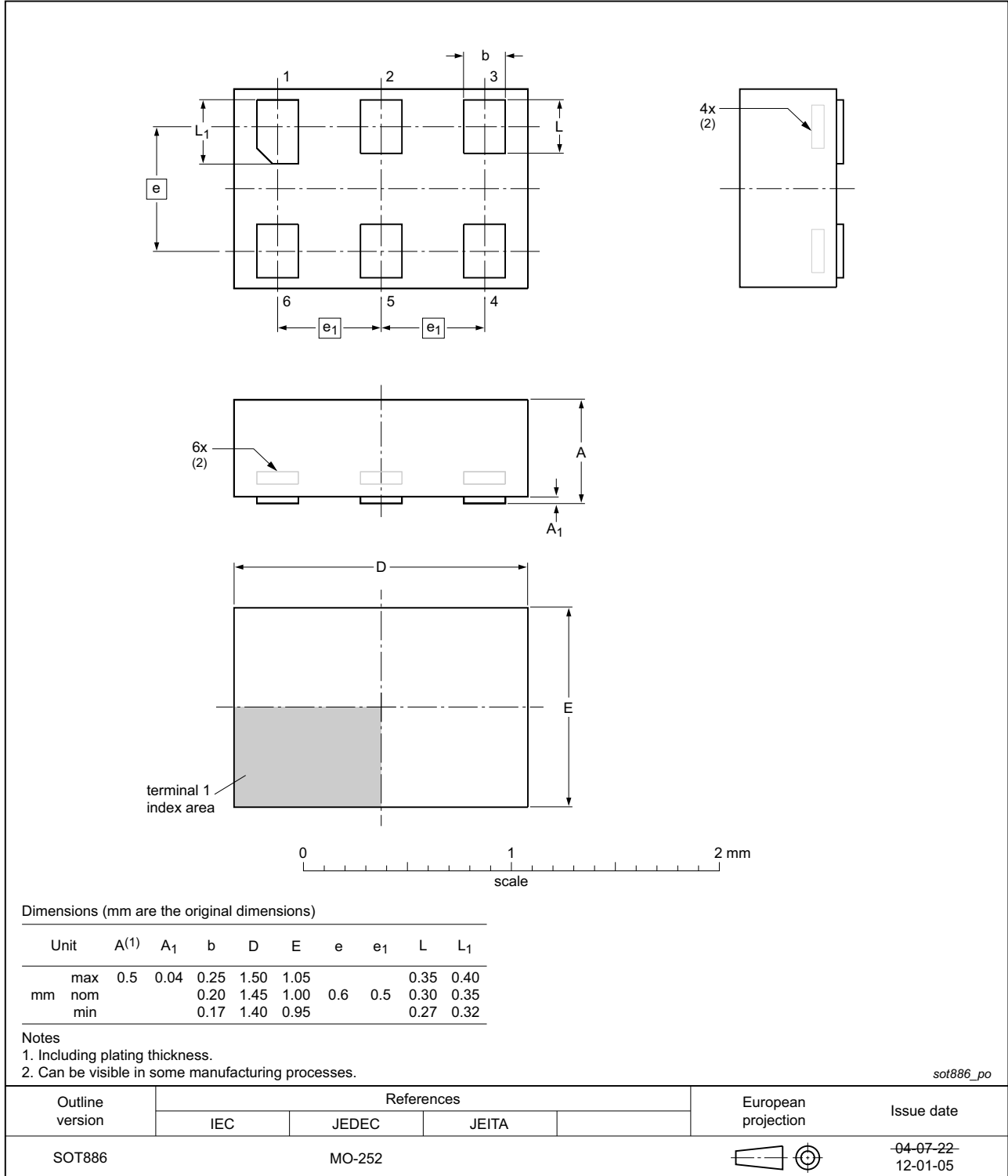


Fig 16. Package outline SOT886 (XSON6)



XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

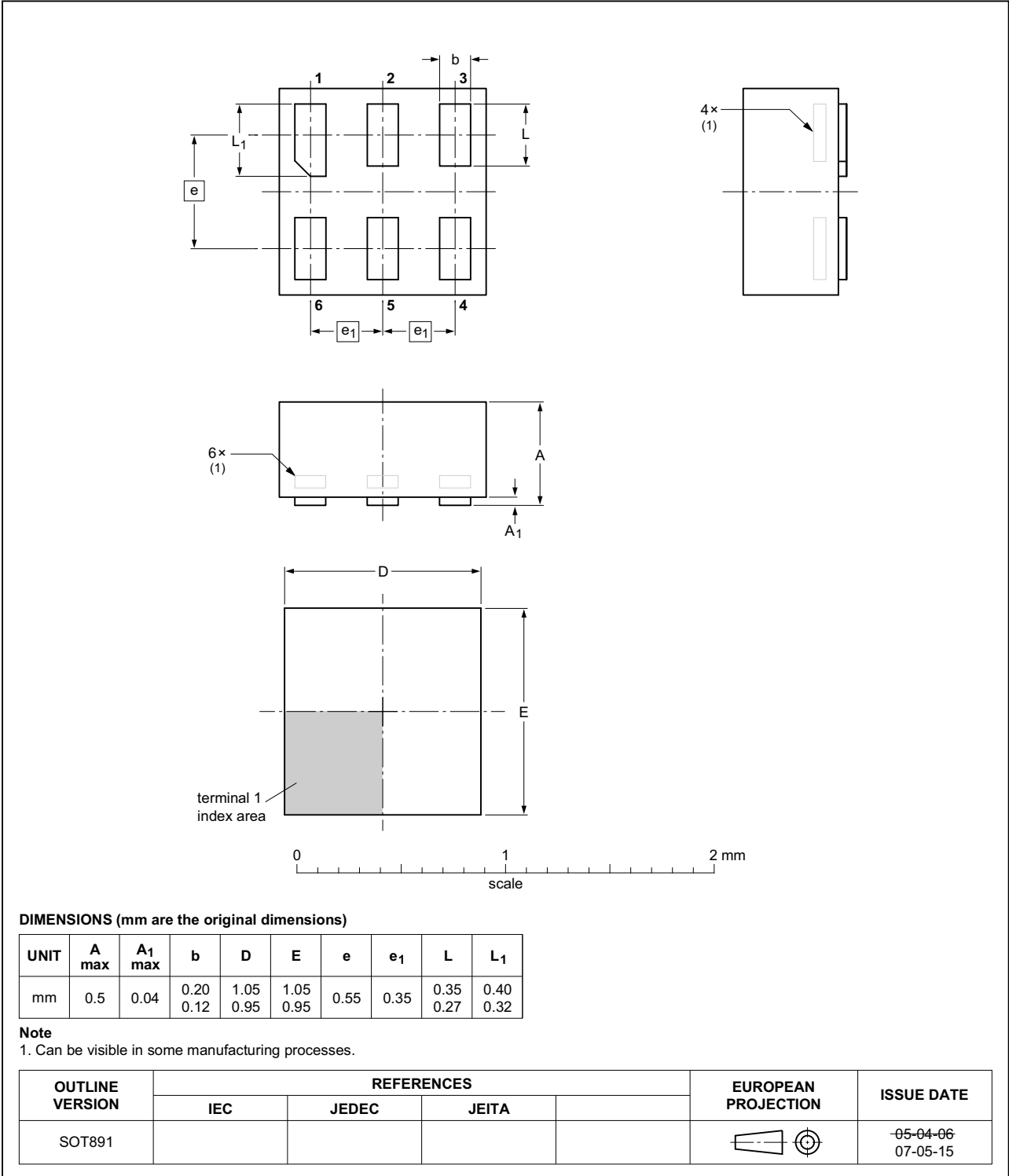


Fig 17. Package outline SOT891 (XSON6)

**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm**

SOT1115

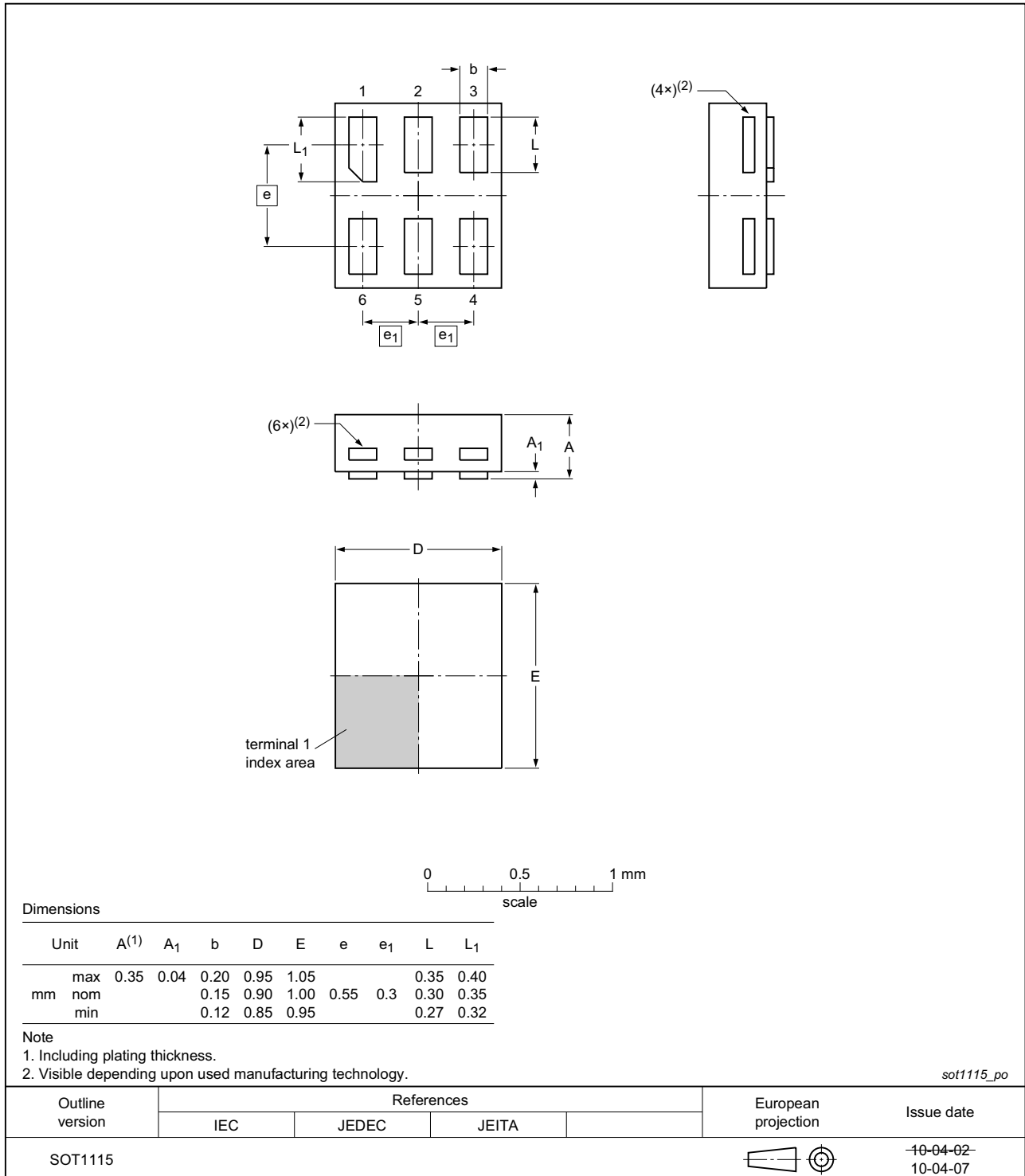


Fig 18. Package outline SOT1115 (XSON6)

**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202

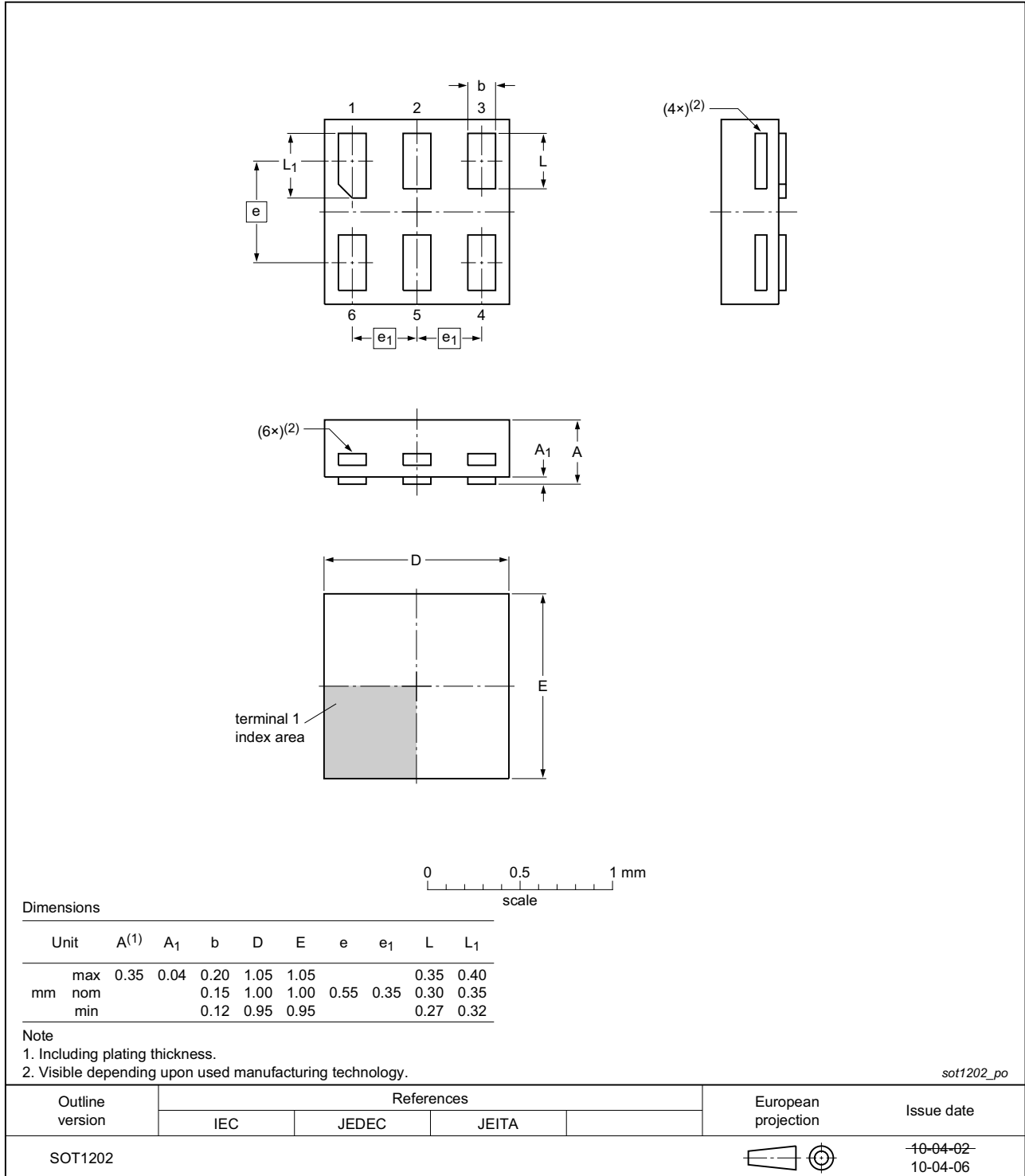


Fig 19. Package outline SOT1202 (XSON6)

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm

SOT1226

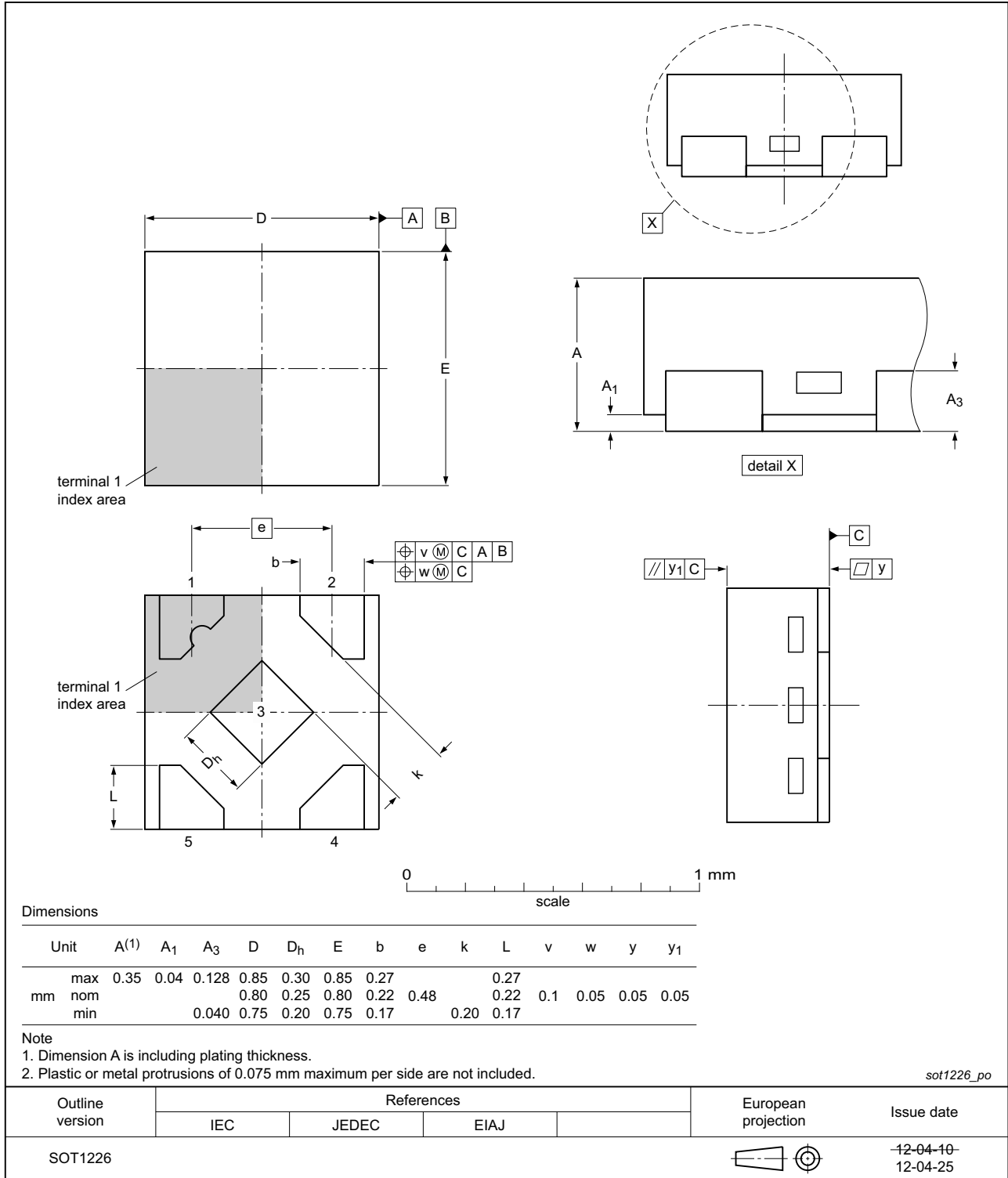


Fig 20. Package outline SOT1226 (X2SON5)

## 17. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 18. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G17 v.8	20150115	Product data sheet	-	74AUP1G17 v.7
Modifications:	<ul style="list-style-type: none"> <li>Marking code <a href="#">Table 2</a>: typo corrected in type number 74AUP1G17GX.</li> </ul>			
74AUP1G17 v.7	20120716	Product data sheet	-	74AUP1G17 v.6
Modifications:	<ul style="list-style-type: none"> <li>Package outline drawing of SOT1226 (<a href="#">Figure 20</a>) modified.</li> </ul>			
74AUP1G17 v.6	20120412	Product data sheet	-	74AUP1G17 v.5
Modifications:	<ul style="list-style-type: none"> <li>Added type number 74AUP1G17GX (SOT1226)</li> <li>Package outline drawing of SOT886 (<a href="#">Figure 16</a>) modified.</li> </ul>			
74AUP1G17 v.5	20111124	Product data sheet	-	74AUP1G17 v.4
Modifications:	<ul style="list-style-type: none"> <li>Legal pages updated.</li> </ul>			
74AUP1G17 v.4	20100715	Product data sheet	-	74AUP1G17 v.3
74AUP1G17 v.3	20090710	Product data sheet	-	74AUP1G17 v.2
74AUP1G17 v.2	20060727	Product data sheet	-	74AUP1G17 v.1
74AUP1G17 v.1	20050726	Product data sheet	-	-

## 19. Legal information

### 19.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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